



ULTRA LOW PHASE NOISE AMPLIFIER MODULE, 1.5 - 5 GHz

Features

Ultra Low Phase Noise: -163 dBc/Hz @ 1 kHz

Gain: 14 dB

Output Power: +22 dBm

Single Supply Voltage: +7V @ 170mA

Hermetically Sealed Module

-55 °C to +85 °C Operating Temperature

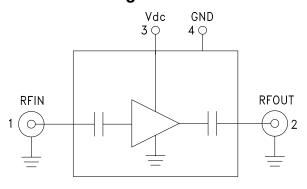


Typical Applications

The HMC-C077 is ideal for:

- Microwave Radio
- Military & Space
- Test Instrumentation
- VSAT

Functional Diagram



General Description

The HMC-C077 is a GaAs HBT Ultra Low Noise Amplifier in a miniature, hermetic module designed to operate between 1.5 and 5 GHz. This high dynamic range amplifier module provides 14 dB of gain, 4.5 dB noise figure and up to +22 dBm of output power with a single supply of +7V. The ultra low phase noise contribution of -163 dBc/Hz at 1 kHz offset, enables superior modulation accuracy within transceiver architectures. The wideband distributed amplifier I/O's are internally matched to 50 Ohms and DC blocked for robust performance. The module features removable SMA connectors which can be detached to allow direct connection of the I/O pins to a microstrip or coplanar circuit.

Electrical Specifications, $T_A = +25$ °C, Vdc = +7V

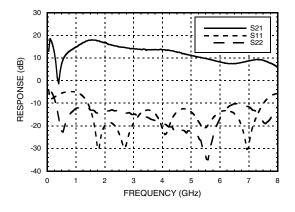
Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range		1.5 - 5			2 - 4		GHz
Gain	9	14		11	14		dB
Gain Flatness		±3.5			±1.5		dB
Gain Variation Over Temperature		0.01			0.01		dB/ °C
Noise Figure		4.5			4		dB
Input Return Loss		19			19		dB
Output Return Loss		15			15		dB
Output Power for 1 dB Compression (P1dB)	15	17		15	17		dBm
Output Power			22			22	dBm
Output Third Order Intercept (IP3)		27			27		dBm
Phase Noise @ 1 kHz, Pout = +22 dBm		-163			-163		dBc/Hz
Phase Noise @ 10 kHz, Pout = +22 dBm		-171			-171		dBc/Hz
Phase Noise @ 100 kHz, Pout = +22 dBm		-175			-175		dBc/Hz
Supply Current (all conditions)		170	240		170	240	mA



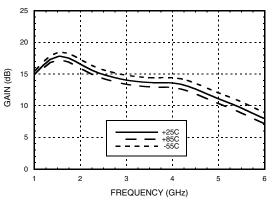


ULTRA LOW PHASE NOISE AMPLIFIER MODULE, 1.5 - 5 GHz

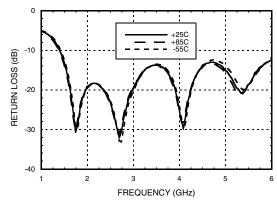
Gain & Return Loss



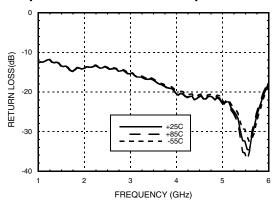
Gain vs. Temperature



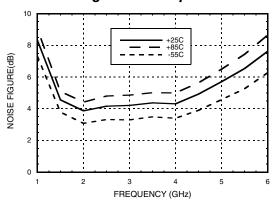
Input Return Loss vs. Temperature



Output Return Loss vs. Temperature



Noise Figure vs. Temperature

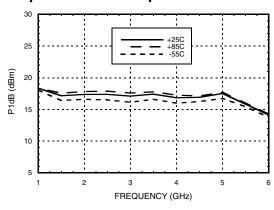




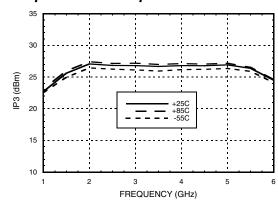


ULTRA LOW PHASE NOISE AMPLIFIER MODULE, 1.5 - 5 GHz

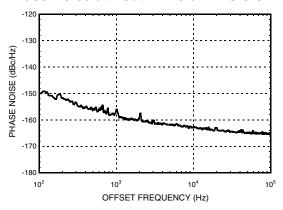
Output P1dB vs. Temperature



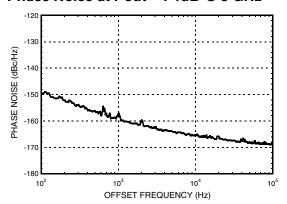
Output IP3 vs. Temperature



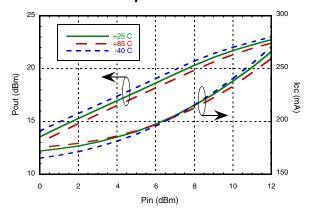
Phase Noise at Pout = +10 dBm @ 3 GHz



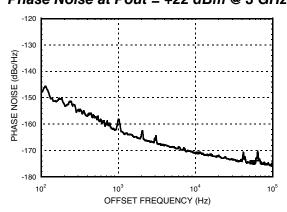
Phase Noise at Pout = P1dB @ 3 GHz



Pout & Icc vs. Temperature



Phase Noise at Pout = +22 dBm @ 3 GHz



AMPLIFIERS



v01.0711



ULTRA LOW PHASE NOISE AMPLIFIER MODULE, 1.5 - 5 GHz

Absolute Maximum Ratings

Bias Supply Voltage (Vdc)	+9V	
RF Output Power (RFOUT)	+22 dBm	
RF Input Power (RFIN)	+15 dBm	
Continuous Pdiss (T = 85 °C)	1.6W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-55 to +85 °C	
ESD Sensitivity (HBM)	Class 1A	
	RF Output Power (RFOUT) RF Input Power (RFIN) Continuous Pdiss (T = 85 °C) Storage Temperature Operating Temperature	



Pin Descriptions

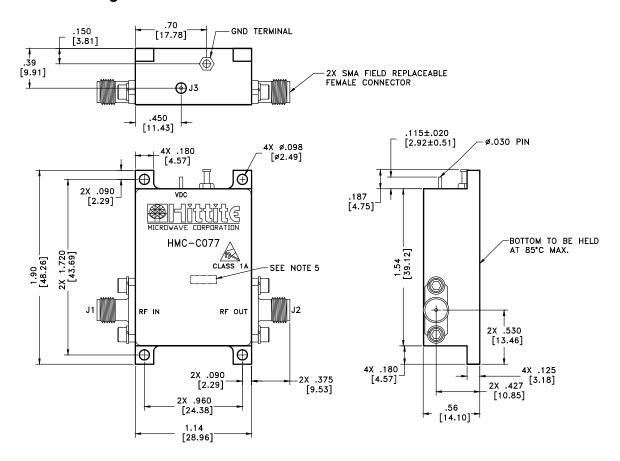
Pin Number	Function	Description	Interface Schematic	
1	RFIN & RF Ground	RF input connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	RFINO————————————————————————————————————	
2	RFOUT & RF Ground	RF output connector, coaxial female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	→ ├─○ RFOUT	
3	Vdc	Power supply voltage for the amplifier. (+7V to +9V)	Vdc O	
4	GND	Power supply ground.	GND =	





ULTRA LOW PHASE NOISE AMPLIFIER MODULE, 1.5 - 5 GHz

Outline Drawing



Package Information

Package Type	C-16
Package Weight	107 gms ^[1]

[1] ±1 gms Tolerance

NOTES

- 1. PACKAGE, LEADS, COVER MATERIAL: KOVAR™
- 2. FINISH: GOLD PLATE OVER NICKEL PLATE.
- 3. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 4. TOLERANCES:
 - 4.1 .XX = ±.02
 - $4.2.XXX = \pm.010$
- 5. MARK LOT NUMBER ON 0.080 X 0.250 LABEL WHERE SHOWN, WITH 0.030" MIN TEXT HEIGHT.



AMPLIFIERS -

ULTRA LOW PHASE NOISE AMPLIFIER MODULE, 1.5 - 5 GHz



ANALOGDEVICES

Notes: